

# Octal D Flip-Flop with 3-State Outputs

## MC74AC574, MC74ACT574

The MC74AC574/74ACT574 is a high–speed, low power octal flip–flop with a buffered common Clock (CP) and a buffered common Output Enable ( $\overline{\rm OE}$ ). The information presented to the D inputs is stored in the flip–flops on the LOW–to–HIGH Clock (CP) transition.

The MC74AC574/74ACT574 is functionally identical to the MC74AC374/74ACT374 except for the pinouts.

#### **Features**

- Inputs and Outputs on Opposite Sides of Package Allowing Easy Interface with Microprocessors
- Useful as Input or Output Port for Microprocessors
- Functionally Identical to MC74AC374/74ACT374
- 3-State Outputs for Bus-Oriented Applications
- Outputs Source/Sink 24 mA
- 'ACT574 Has TTL Compatible Inputs
- Pb-Free Packages are Available

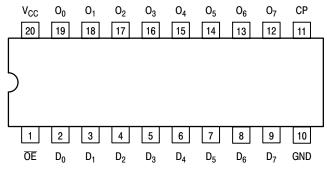


Figure 1. Pinout: 20-Lead Packages Conductors

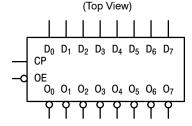


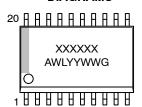
Figure 2. Logic Symbol

#### **PIN ASSIGNMENT**

PIN	FUNCTION				
D <sub>0</sub> -D <sub>7</sub>	Data Inputs				
СР	Clock Pulse Input				
ŌĒ	3-State Output Enable Input				
O <sub>0</sub> -O <sub>7</sub>	3-State Outputs				

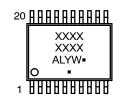
#### MARKING DIAGRAMS







TSSOP-20 DT SUFFIX CASE 948E



XXXXXX = Specific Device Code A = Assembly Location

WL, L = Wafer Lot
YY, Y = Year
WW, W = Work Week
G or = Pb-Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

#### **FUNCTIONAL DESCRIPTION**

The MC74AC574/74ACT574 consists of eight edge-triggered flip-flops with individual D-type inputs and 3-state true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ( $\overline{OE}$ ) LOW, the contents of the eight flip-flops are available at the outputs. When  $\overline{OE}$  is HIGH, the outputs go to the high impedance state. Operation of the  $\overline{OE}$  input does not affect the state of the flip-flops.

#### **FUNCTION TABLE**

	Inputs		Internal	Outputs	Function
ŌĒ	CP	D	Q	O <sub>n</sub>	runction
Н	Н	L	NC	Z	Hold
Н	Н	Н	NC	Z	Hold
Н	」	L	L	Z	Load
Н	」	Н	Н	Z	Load
L	」	L	L	L	Data Available
L	」	Н	Н	Н	Data Available
L	Н	L	NC	NC	No Change in Data
L	Н	Н	NC	NC	No Change in Data

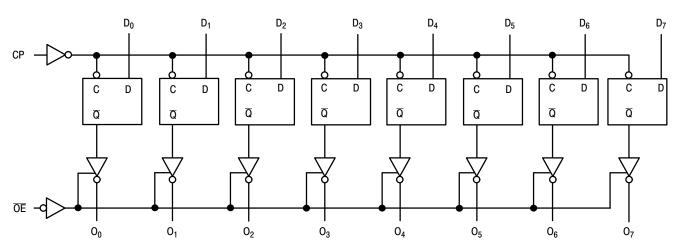
H = HIGH Voltage Level

L = LOW Voltage Level

X = Immaterial

Z = High Impedance

NC = No Change



NOTE: This diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Figure 3. Logic Diagram

#### **MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage (Referenced to GND)	-0.5 to +6.5	V
V <sub>IN</sub>	DC Input Voltage (Referenced to GND)	-0.5 to V <sub>CC</sub> +0.5	V
V <sub>OUT</sub>	DC Output Voltage (Referenced to GND)	-0.5 to V <sub>CC</sub> +0.5	V
I <sub>IN</sub>	DC Input Current, per Pin	±20	mA
I <sub>OUT</sub>	I <sub>OUT</sub> DC Output Sink/Source Current, per Pin		mA
I <sub>CC</sub>	I <sub>CC</sub> DC V <sub>CC</sub> or GND Current per Output Pin		mA
T <sub>stg</sub>	Storage Temperature	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Тур	Max	Unit
V	Cupply Voltage	'AC	2.0	5.0	6.0	V
V <sub>CC</sub>	Supply Voltage	'ACT	4.5	5.0	5.5	V
V <sub>IN</sub> , V <sub>OUT</sub>	DC Input Voltage, Output Voltage (Ref. to GND)		0	=	V <sub>CC</sub>	V
		V <sub>CC</sub> @ 3.0 V	-	150	=	
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time (Note 1)  'AC Devices except Schmitt Inputs	V <sub>CC</sub> @ 4.5 V	-	40	=	ns/V
	7.6 Devides except estimating inputs	V <sub>CC</sub> @ 5.5 V	-	25	=	
	Input Rise and Fall Time (Note 2)	V <sub>CC</sub> @ 4.5 V	-	10	=	0 /
t <sub>r</sub> , t <sub>f</sub>	'ACT Devices except Schmitt Inputs	V <sub>CC</sub> @ 5.5 V	-	8.0	=	ns/V
T <sub>A</sub>	Operating Ambient Temperature Range	-40	25	85	°C	
I <sub>OH</sub>	Output Current – High	-	-	-24	mA	
l <sub>OL</sub>	Output Current – Low		_	_	24	mA

V<sub>IN</sub> from 30% to 70% V<sub>CC</sub>; see individual Data Sheets for devices that differ from the typical input rise and fall times.
 V<sub>IN</sub> from 0.8 V to 2.0 V; see individual Data Sheets for devices that differ from the typical input rise and fall times.

#### **DC CHARACTERISTICS**

			74	AC	74AC			
Symbol	Parameter	V <sub>CC</sub>	T <sub>A</sub> = +25°C		T <sub>A</sub> = -40°C to +85°C	Unit	Conditions	
		(V)	Тур	G	uaranteed Limits			
V <sub>IH</sub>	Minimum High Level	3.0	1.5	2.1	2.1		V <sub>OUT</sub> = 0.1 V	
	Input Voltage	4.5	2.25	3.15	3.15	V	or V <sub>CC</sub> – 0.1 V	
		5.5	2.75	3.85	3.85			
V <sub>IL</sub>	Maximum Low Level	3.0	1.5	0.9	0.9		V <sub>OUT</sub> = 0.1 V	
	Input Voltage	4.5	2.25	1.35	1.35	V	or V <sub>CC</sub> – 0.1 V	
		5.5	2.75	1.65	1.65			
V <sub>OH</sub>	Minimum High Level	3.0	2.99	2.9	2.9		I <sub>OUT</sub> = -50 μA	
	Output Voltage	4.5	4.49	4.4	4.4	V		
		5.5	5.49	5.4	5.4			
							$*V_{IN} = V_{IL} \text{ or } V_{IH}$	
		3.0	_	2.56	2.46		-12 mA	
		4.5	_	3.86	3.76	V	I <sub>OH</sub> –24 mA	
		5.5	_	4.86	4.76		-24 mA	
V <sub>OL</sub>	Maximum Low Level	3.0	0.002	0.1	0.1		I <sub>OUT</sub> = 50 μA	
	Output Voltage	4.5	0.001	0.1	0.1	V		
		5.5	0.001	0.1	0.1			
							*V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub>	
		3.0	_	0.36	0.44	V	12 mA	
		4.5	_	0.36	0.44	V	I <sub>OL</sub> 24 mA	
		5.5	-	0.36	0.44		24 mA	
I <sub>IN</sub>	Maximum Input Leakage Current	5.5	-	±0.1	±1.0	μΑ	V <sub>I</sub> = V <sub>CC</sub> , GND	
I <sub>OLD</sub>	†Minimum Dynamic	5.5	-	-	75	mA	V <sub>OLD</sub> = 1.65 V Max	
I <sub>OHD</sub>	Output Current	5.5	_	-	-75	mA	V <sub>OHD</sub> = 3.85 V Mir	
I <sub>CC</sub>	Maximum Quiescent Supply Current	5.5	-	8.0	80	μΑ	V <sub>IN</sub> = V <sub>CC</sub> or GND	
	1		1				1	

<sup>\*</sup> All outputs loaded; thresholds on input associated with output under test. †Maximum test duration 2.0 ms, one output loaded at a time.

NOTE: Note:  $I_{IN}$  and  $I_{CC}$  @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V  $V_{CC}$ .

#### AC CHARACTERISTICS (For Figures and Waveforms - See AND8277/D at www.onsemi.com)

				74AC		74	AC		
Symbol	Parameter	V <sub>CC</sub> * (V)		Γ <sub>A</sub> = +25°( C <sub>L</sub> = 50 pf		T <sub>A</sub> = -40°C C <sub>L</sub> = 5		Unit	Fig. No.
			Min	Тур	Max	Min	Max		
f <sub>max</sub>	Maximum Clock Frequency	3.3 5.0	75 95	-	- -	60 85	-	MHz	3–3
t <sub>PLH</sub>	Propagation Delay CP to O <sub>n</sub>	3.3 5.0	3.5 2.0		13.5 9.5	3.5 2.0	15 11	ns	3–6
t <sub>PHL</sub>	Propagation Delay CP to O <sub>n</sub>	3.3 5.0	3.5 2.0	-	12 8.5	3.5 2.0	13.5 9.5	ns	3–6
t <sub>PZH</sub>	Output Enable Time	3.3 5.0	2.5 2.0	-	11 8.5	2.5 2.0	12 9.0	ns	3–7
t <sub>PZL</sub>	Output Enable Time	3.3 5.0	3.0 1.5	-	10.5 8.0	3.5 2.0	11.5 9.0	ns	3–8
t <sub>PHZ</sub>	Output Disable Time	3.3 5.0	4.0 2.0	-	12 9.5	4.5 2.0	13 10.5	ns	3–7
t <sub>PLZ</sub>	Output Disable Time	3.3 5.0	2.0 1.5	- -	9.0 7.5	2.5 1.5	10 8.5	ns	3–8

<sup>\*</sup> Voltage Range 3.3 V is 3.3 V  $\pm$ 0.3 V. Voltage Range 5.0 V is 5.0 V  $\pm$ 0.5 V.

#### **AC OPERATING REQUIREMENTS**

			74AC		74AC		
Symbol	Parameter	$V_{CC}^*$ $T_A = +25^{\circ}C$ $C_L = 50 \text{ pF}$		T <sub>A</sub> = -40°C to +85°C C <sub>L</sub> = 50 pF	Unit	Fig. No.	
			Тур	Gua	ranteed Minimum		
t <sub>s</sub>	Setup Time, HIGH or LOW D <sub>n</sub> to CP	3.3 5.0	-	2.5 1.5	3.0 2.0	ns	3–9
t <sub>h</sub>	Hold Time, HIGH or LOW D <sub>n</sub> to CP	3.3 5.0	-	1.5 1.5	1.5 1.5	ns	3–9
t <sub>w</sub>	CP Pulse Width HIGH or LOW	3.3 5.0	- -	6.0 4.0	7.0 5.0	ns	3–6

<sup>\*</sup>Voltage Range 3.3 V is 3.3 V  $\pm 0.3$  V. Voltage Range 5.0 V is 5.0 V  $\pm 0.5$  V.

#### **DC CHARACTERISTICS**

			74	CT	74ACT			
Symbol	Parameter	V <sub>CC</sub> (V)	T <sub>A</sub> = -	+25°C	T <sub>A</sub> = -40°C to +85°C	Unit	Conditions	
		(*)	Тур	Gu	aranteed Limits			
V <sub>IH</sub>	Minimum High Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	٧	V <sub>OUT</sub> = 0.1 V or V <sub>CC</sub> - 0.1 V	
V <sub>IL</sub>	Maximum Low Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	٧	V <sub>OUT</sub> = 0.1 V or V <sub>CC</sub> - 0.1 V	
V <sub>OH</sub>	Minimum High Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	٧	I <sub>OUT</sub> = -50 μA	
		4.5 5.5	- -	3.86 4.86	3.76 4.76	V	$*V_{IN} = V_{IL} \text{ or } V_{IH}$ $I_{OH}$ -24 mA -24 mA	
V <sub>OL</sub>	Maximum Low Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	٧	I <sub>OUT</sub> = 50 μA	
		4.5 5.5	- -	0.36 0.36	0.44 0.44	V	$*V_{IN} = V_{IL} \text{ or } V_{IH}$ $24 \text{ mA}$ $I_{OL} \qquad 24 \text{ mA}$	
I <sub>IN</sub>	Maximum Input Leakage Current	5.5	-	±0.1	±1.0	μΑ	$V_I = V_{CC}$ , GND	
$\Delta I_{CCT}$	Additional Max. I <sub>CC</sub> /Input	5.5	0.6		1.5	mA	V <sub>I</sub> = V <sub>CC</sub> - 2.1 V	
I <sub>OZ</sub>	Maximum 3-State Current	5.5	-	±0.5	±5.0	μΑ	$\begin{aligned} &V_{I}\left(OE\right) = V_{IL}, V_{IH} \\ &V_{I} = V_{CC},  GND \\ &V_{O} = V_{CC},  GND \end{aligned}$	
I <sub>OLD</sub>	†Minimum Dynamic	5.5	-	-	75	mA	V <sub>OLD</sub> = 1.65 V Max	
I <sub>OHD</sub>	Output Current	5.5	-	-	-75	mA	V <sub>OHD</sub> = 3.85 V Mir	
I <sub>CC</sub>	Maximum Quiescent Supply Current	5.5	_	8.0	80	μΑ	V <sub>IN</sub> = V <sub>CC</sub> or GND	

<sup>\*</sup>All outputs loaded; thresholds on input associated with output under test. †Maximum test duration 2.0 ms, one output loaded at a time.

### AC CHARACTERISTICS (For Figures and Waveforms - See AND8277/D at www.onsemi.com)

				74ACT		74 <b>A</b>	CT		
Symbol	Parameter	V <sub>CC</sub> * (V)			T <sub>A</sub> = -40°C to +85°C C <sub>L</sub> = 50 pF		Unit	Fig. No.	
			Min	Тур	Max	Min	Max		
f <sub>max</sub>	Maximum Clock Frequency	5.0	100	-	-	85	-	ns	3–3
t <sub>PLH</sub>	Propagation Delay CP to O <sub>n</sub>	5.0	2.5	-	11	2.0	12	ns	3–6
t <sub>PHL</sub>	Propagation Delay CP to O <sub>n</sub>	5.0	2.0	-	10	1.5	11	ns	3–6
t <sub>PZH</sub>	Output Enable Time	5.0	2.0	-	9.5	1.5	10	ns	3–7
t <sub>PZL</sub>	Output Enable Time	5.0	2.0	_	9.0	1.5	10	ns	3–8
t <sub>PHZ</sub>	Output Disable Time	5.0	2.0	-	10.5	1.5	11.5	ns	3–7
t <sub>PLZ</sub>	Output Disable Time	5.0	2.0	-	8.5	1.5	9.0	ns	3–8

<sup>\*</sup>Voltage Range 5.0 V is 5.0 V ±0.5 V.

#### **AC OPERATING REQUIREMENTS**

				74ACT	74ACT				
Symbol	Parameter	V <sub>CC</sub> * (V)							Fig. No.
			Тур	Guaran	teed Minimum				
t <sub>s</sub>	Setup Time, HIGH or LOW D <sub>n</sub> to CP	5.0	-	2.5	2.5	ns	3–9		
t <sub>h</sub>	Hold Time, HIGH or LOW D <sub>n</sub> to CP	5.0	-	1.0	1.0	ns	3–9		
t <sub>w</sub>	CP Pulse Width HIGH or LOW	5.0	ı	3.0	4.0	ns	3–6		

<sup>\*</sup>Voltage Range 3.3 V is 3.3 V  $\pm 0.3$  V. Voltage Range 5.0 V is 5.0 V  $\pm 0.5$  V.

#### **CAPACITANCE**

Symbol	Parameter	Value Typ	Unit	Test Conditions
C <sub>IN</sub>	Input Capacitance	4.5	pF	V <sub>CC</sub> = 5.0 V
C <sub>PD</sub>	Power Dissipation Capacitance	40	pF	V <sub>CC</sub> = 5.0 V

#### **ORDERING INFORMATION**

Device	Marking	Package	Shipping <sup>†</sup>
MC74AC574DWG	AC574	SOIC-20	38 Units / Rail
MC74AC574DWR2G	AC574	SOIC-20	1000 / Tape & Reel
MC74ACT574DWG	ACT574	SOIC-20	38 Units / Rail
MC74ACT574DWR2G	ACT574	SOIC-20	1000 / Tape & Reel
MC74AC574DTR2G	AC 574	TSSOP-20	2500 / Tape & Reel
MC74ACT574DTR2G	ACT 574	TSSOP-20	2500 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

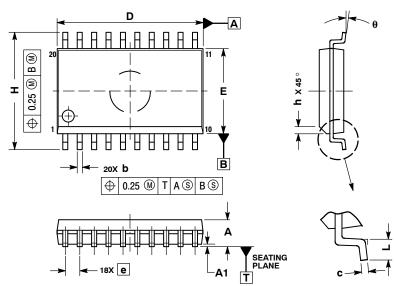




SOIC-20 WB CASE 751D-05 **ISSUE H** 

**DATE 22 APR 2015** 

#### SCALE 1:1



- DIMENSIONS ARE IN MILLIMETERS.
   INTERPRET DIMENSIONS AND TOLERANCES.
- PER ASME Y14.5M, 1994.
  3. DIMENSIONS D AND E DO NOT INCLUDE MOLD
- PROTRUSION.
  MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
- DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL

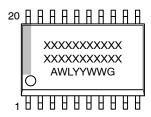
	MILLIMETERS			
DIM	MIN	MAX		
Α	2.35	2.65		
A1	0.10	0.25		
b	0.35	0.49		
С	0.23	0.32		
D	12.65	12.95		
E	7.40	7.60		
е	1.27 BSC			
Н	10.05	10.55		
h	0.25	0.75		
L	0.50	0.90		
A	0 °	7 °		

#### **RECOMMENDED SOLDERING FOOTPRINT\***



DIMENSIONS: MILLIMETERS

#### **GENERIC MARKING DIAGRAM\***



XXXXX = Specific Device Code = Assembly Location

WL = Wafer Lot ΥY = Year WW = Work Week = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	SOIC-20 WB		PAGE 1 OF 1

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<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



#### TSSOP-20 WB CASE 948E ISSUE D

**DATE 17 FEB 2016** 





#### NOTES:

- DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
- 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
- FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K
- (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
- TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

  7. DIMENSION A AND B ARE TO BE
- DETERMINED AT DATUM PLANE -W-

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	6.40	6.60	0.252	0.260
В	4.30	4.50	0.169	0.177
С		1.20		0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
Н	0.27	0.37	0.011	0.015
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

#### **SOLDERING FOOTPRINT**



#### **GENERIC MARKING DIAGRAM\***



= Assembly Location

= Wafer Lot

= Year

= Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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